VS-STPS20L15G-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 20 A



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PRIMARY CHARACTERISTICS								
I _{F(AV)}	20 A							
V _R	15 V							
V _F at I _F	0.33 V							
I _{RM} max.	600 mA at 100 °C							
T _J max.	125 °C							
E _{AS}	10 mJ							
Package	D ² PAK (TO-263AB)							
Circuit configuration	Single							

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- Center tap module
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	A						
V _{RRM}		15	V						
I _{FSM}	t _p = 5 μs sine	700	A						
V _F	19 A_{pk} , $T_J = 125 \text{ °C}$ (typical)	0.25	V						
TJ	Range	-55 to +125	D°						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VS-STPS20L15G-M3	UNITS					
Maximum DC reverse voltage	V _R	T.I = 100 °C	15	V					
Maximum working peak reverse voltage	V _{RWM}	ij=100 C	10	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 85 °C, red	20						
Maximum peak one cycle	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	700	А				
non-repetitive surge current See fig. 7		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH	10	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in Frequency limited by T_J maximum	2	А					

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS				
Forward voltage drop See fig. 1		19 A	T.I = 25 °C	-	0.41	v			
	V _{FM} ⁽¹⁾	40 A	1j=25 0	-	0.52				
	VFM (*)	19 A	T,I = 125 °C	0.25	0.33				
		40 A	1j = 125 C	0.37	0.50				
Reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	10	mA			
See fig. 2	IRM (1)	T _J = 100 °C	V _R = naleu V _R	-	600	III/A			
Threshold voltage	V _{F (TO)}	⁽⁰⁾ T T movimum 0.182		182	V				
Forward slope resistance	r _t	ij = ijinaximum	$T_J = T_J maximum$						
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	-	2000	pF				
Typical series inductance	L _S	Measured lead to lead 5 n	8	-	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

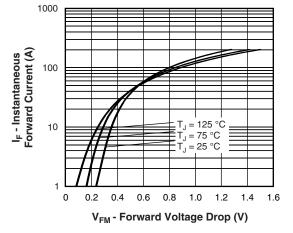
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction temperature range	TJ		-55 to +125	ာိ					
Maximum storage temperature range	T _{Stg}		-55 to +150	C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5						
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W					
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40						
Approximate weight			2	g					
Approximate weight			0.07	oz.					
Mounting torque	1	Non-lubricated threads	6 (5)	kgf ⋅ cm					
Mounting torque maximun	ו	Non-Iudricated trifeads	12 (10)	(lb̃f ⋅ in)					
Marking device		Case style D ² PAK (TO-263AB)	STPS2	0L15G					

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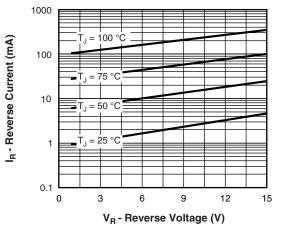
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Fig. 1 - Maximum Forward Voltage Drop Characteristics





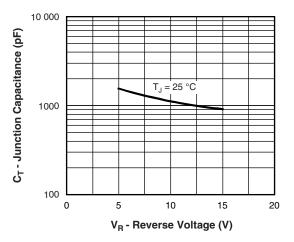


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

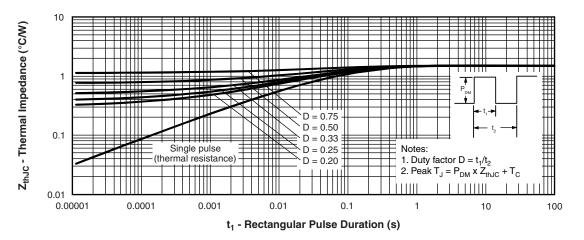


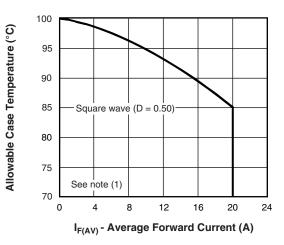
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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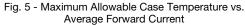
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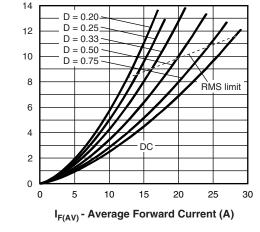
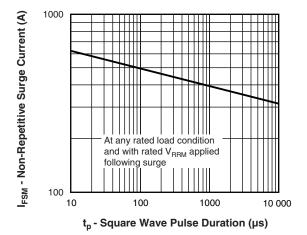


Fig. 6 - Forward Power Loss Characteristics



Average Power Loss (W)

Fig. 7 - Maximum Non-Repetitive Surge Current

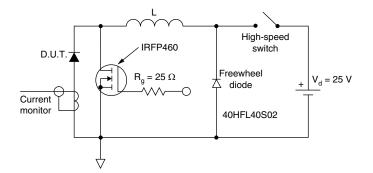


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

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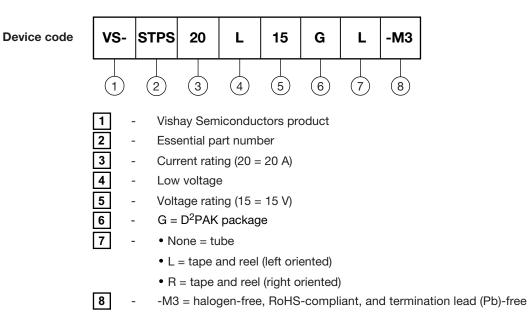
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ORDERING INFORMATION TABLE

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ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-STPS20L15GL-M3	800	13" diameter plastic tape and reel						
VS-STPS20L15G-M3	50	Antistatic plastic tubes						
VS-STPS20L15GR-M3	800	13" diameter plastic tape and reel						

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					

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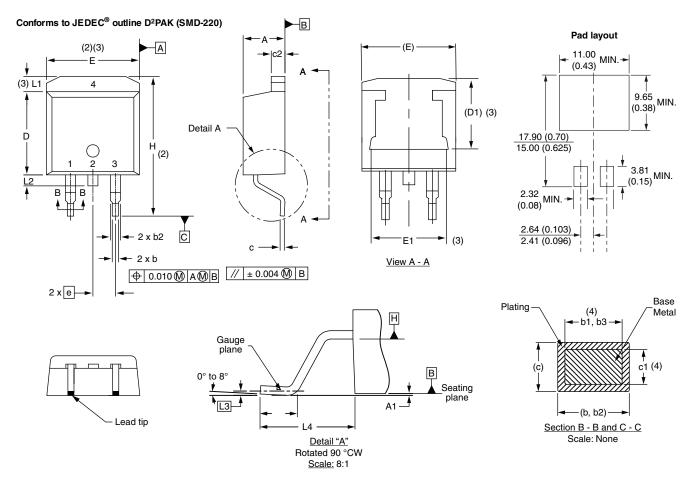


Outline Dimensions

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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3	
A1	0.00	0.254	0.000	0.010		Е	9.65	10.67	0.380	0.420	2, 3	
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3	
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	BSC		
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625		
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110		
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3	
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070		
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC		
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208		

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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